

Anhui Crystro Crystal Materials Co., Ltd.

Lithium Niobate (LiNbO₃)

Introduction:

Lithium Niobate is an inorganic material, chemical formula LiNbO₃, is a negative crystal, ferro-electric crystal, polarization of lithium niobate crystal with piezoelectric, ferro-electric, photoelectric, nonlinear optical, thermo-electric materials, and has optical refractive effect.

Lithium niobate crystal is a good piezoelectric conversion material, ferro-electric materials, electric and optical materials. As electro-optical materials in optical communication, it is widely used in parametric oscillator, double frequency, acoustic and optical devices, and optical modulator. The doping of Mgo can effectively improve the damage resistance valve value of the crystal.



Main Advantages:

- ♦ Very small chirp effect
- ♦ High modulation bandwidth
- ♦ High extinction ratio
- ♦ Stable chemical and physical properties

Typical applications:

- ♦ Acoustic surface wave filter
- ♦ Separator
- ♦ Narrow band filter
- ♦ Sensors
- ♦ Photon tunable filter
- ♦ Acoustic and optical devices
- ♦ Optical gyroscope
- ♦ Optical waveguide
- ♦ Optical switches
- ♦ Optical modulation direction coupler
- ♦ Optical communication modulator
- ♦ Interferometer converter
- ♦ High-speed long-distance communication





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Material Properties:

Crystal Structure	Trigonal
Lattice constant	a=0.515Å, c=13.863Å, Z=6Å
Melting Point	1250±5℃
Curie Point	1140±5℃
Mohs Hardness	5
Density	4.64 g/cm ³
Deliquescence	No
Dielectric Constant	ε11/ε0=85; ε33/ε0=29.5
Thermal Expansion Coefficient	a1=a2=2×10 ⁻⁶ /°C, a3=2.2×10 ⁻⁶ /°C at 25°C
Thermal Conductivity	38 W /m /K @ 25°C
Transmission Range	370-5000nm
Piezoelectric Constant	d22=2.04×10-11C/N,d33=0.6×10-11C/N,d15=7×10-11C/N, d31=-0.1×10-11C/N
E-O Coefficient	gT33=32pm/V, gS33=31pm/V; gT31=10pm/V, gS31=8.6pm/V gT22=6.8pm/V, gS22=3.4pm/V
Refractive Indices	no=2.2827 ± 0.0003 ne=2.1928± 0.0003

Crystro offers:

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Size	4", 6" Boule or wafer, Acoustic or Optical grade
Doping	No Doping or With Mg
Boule Length	≥50mm
Wafer Thickness	0.25, 0.35, 0.50(mm) or upon request
Orientation	Y42°/Y36°/Y128°/X/Y/Z or Upon Request
Surface Process	Single/Double Sides Polishing
TTV	<10µm
BOW	$\pm (25 \mu m \sim 40 \mu m)$
Warp	≤35μm
Flat Width	32.0±2.0 (mm) or Upon Request
Roughness	Ra≤10Å
Chamfer	0.1mm@45° or round edge

Note: Above parameters for reference only, please contact our sales Rep. for your specific requirement.

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